

# GATE 2019 Instrumentation Engineering

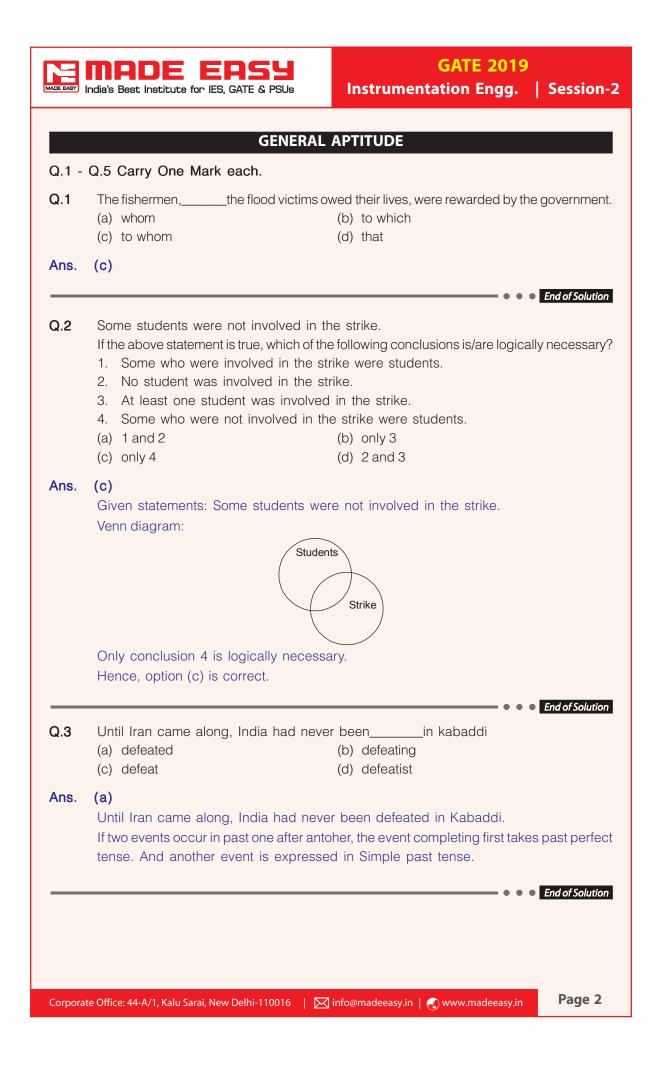
Questions and Solutions of afternoon session

## Date of Exam : 3/2/2019

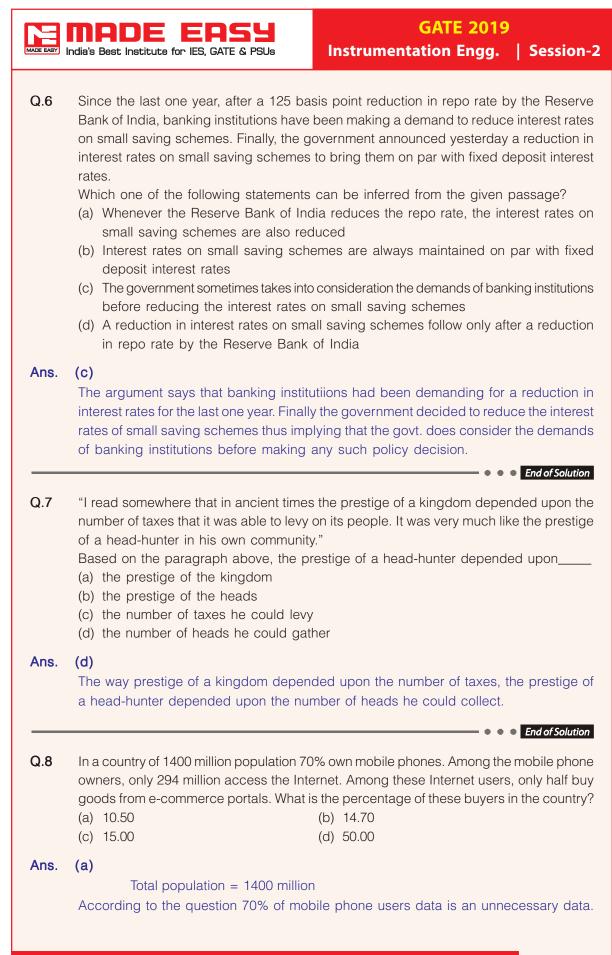
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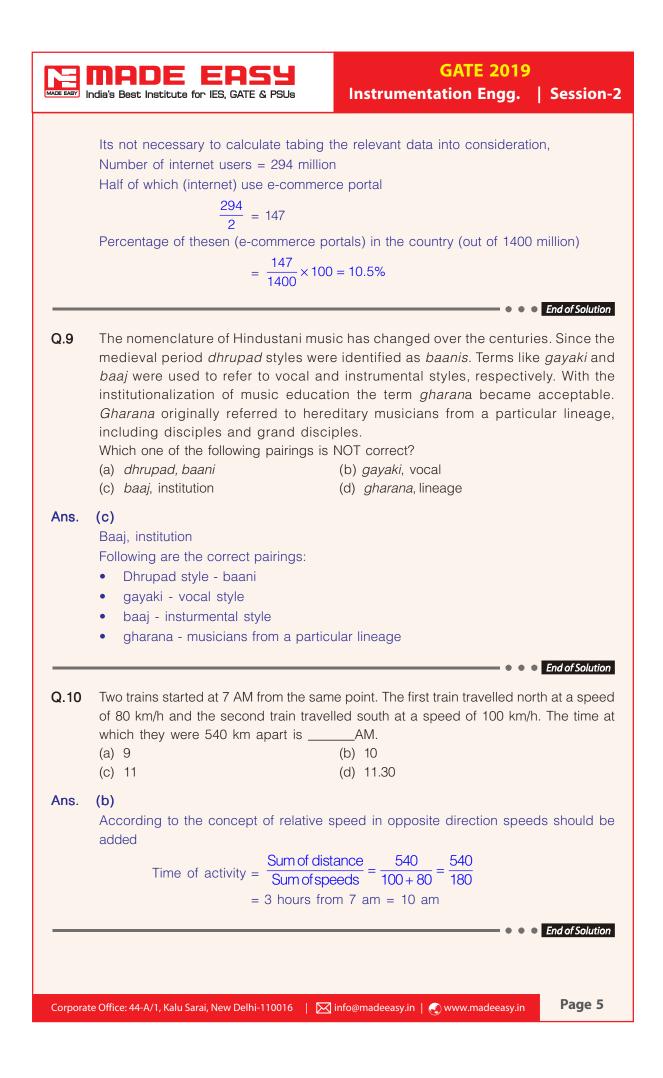


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	India's Best Institute for IES, GATE & PSUs	GATE 2019 Instrumentation Engg.   Session-2					
Q.4	<ul> <li>the directions given below:</li> <li>1. No two odd or even numbers are no</li> <li>2. The second number from the left is</li> <li>3. The middle number is exactly twice</li> <li>Which is the second number from the no</li> <li>(a) 2</li> </ul>	s exactly half of the left-most number. e the right-most number.					
Ans.	(c) According to given data the only possing 10 5 4 7 2 So, second from right will be 7.	ible arrangement is					
Q.5	increase in its volume is (a) 17.1	<ul><li>(b) 21.0</li><li>(d) 72.8</li></ul>					
Ans.	(c)						
	We know formula for volume of a (right circular) cone is $\frac{1}{3}\pi r^2 h$						
	Original volume $(V_0)$						
	$V_0 = \frac{1}{3}\pi r_1^2 h_1$	(i)					
	Now we know radius and height both are increased by 10%. So after increase the new volume will be						
	$V_n = \frac{1}{3}\pi (1.1r_1)^2 (1$	. 1) <i>h</i> <sub>1</sub>					
	$= 1.331 \left(\frac{1}{3}\pi r_1^2\right)$	$h_1$					
	$= 1.331 (V_0)$						
	% change in volume = $\frac{V_n - V_0}{V_0} \times 100$	$0 = \frac{1.331V_0 - V_0}{V_0} \times 100$					







#### **Features :**

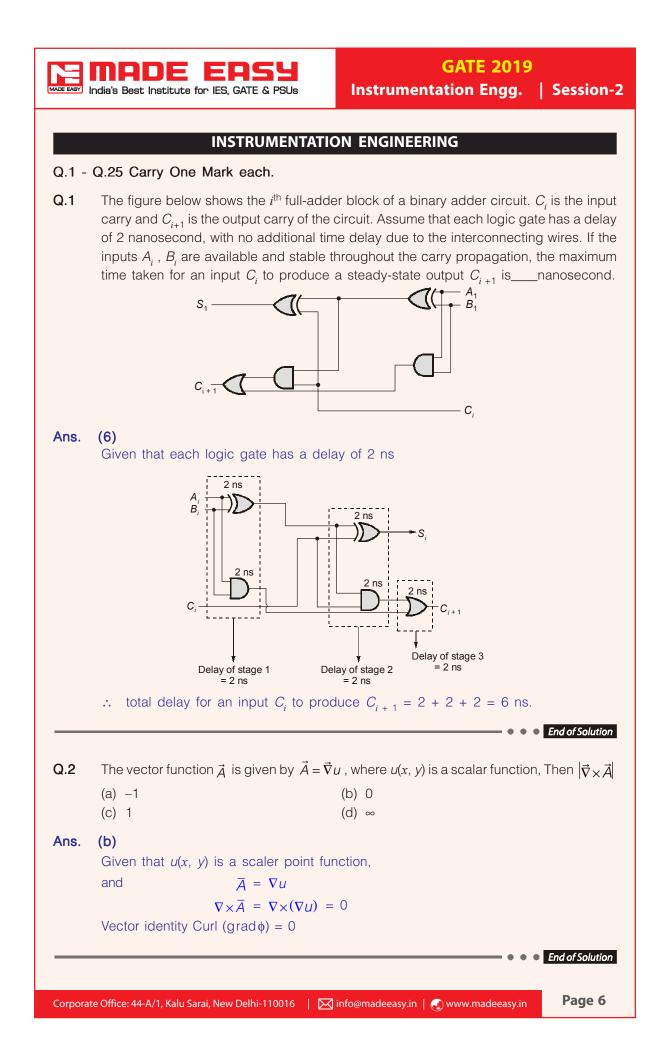
- Very useful to develop numerical solving approach & improving writing skills.
- Special focus on improving answer layout specially for theory questions.
- Classes will be delivered by senior faculties.
- Updated Mains workbook for every subject having varied practice question sets.
- Test series will be conducted on every Sunday in synchronisation with the subject taught in class.
- Discussion on probable questions.
- Comprehensive and in-depth discussion on variety of conventional questions, thus strengthening fundamental concepts.

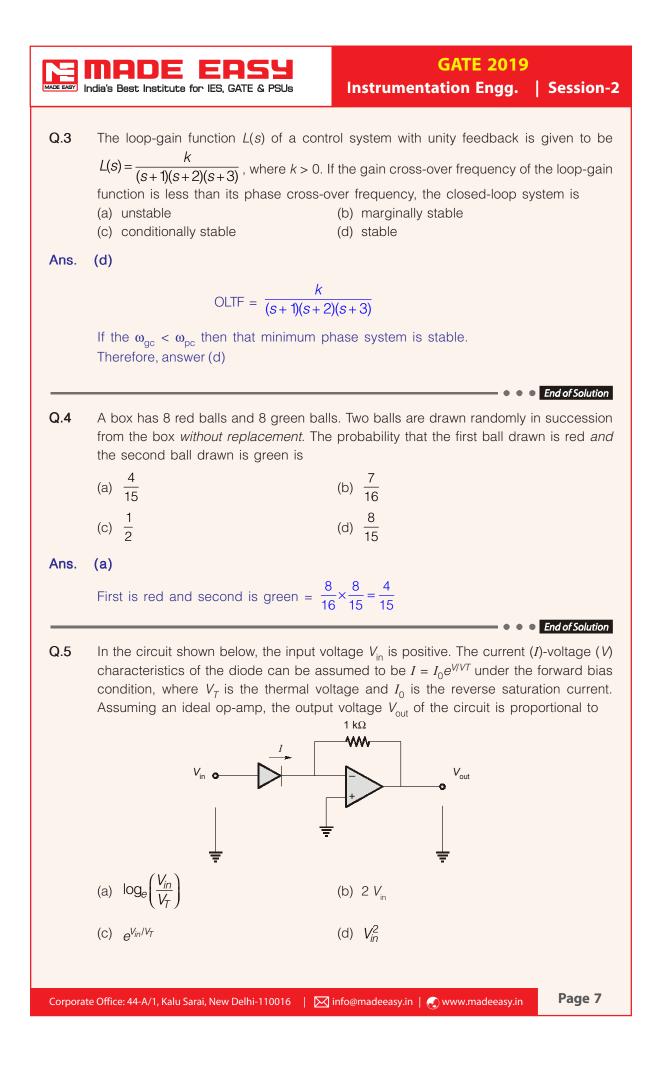
Batch Details						
Streams	Batch Code Batch Commencing D		encing Date	Venue (Delhi)	Timing	
ME	A	20-Feb	2019	Ghitorni Centre	7:30 AM to 1:30 PM	
ME	В	20-Feb-2019		Ghitorni Centre	3:00 PM to 9:00 PM	
ME	С	20-Feb-2019		Saket Centre	7:30 AM to 1:30 PM	
CE	A	21-Feb-2019		Ignou Road Centre	7:30 AM to 1:30 PM	
CE	В	21-Feb-2019		Kalu Sarai Centre	3:00 PM to 9:00 PM	
EE	A	22-Feb	2019	Lado Sarai Centre	7:30 AM to 1:30 PM	
EE	В	22-Feb	2019	Kalu Sarai Centre	3:00 PM to 9:00 PM	
EC	A	22-Feb-	2019	Lado Sarai Centre	7:30 AM to 1:30 PM	

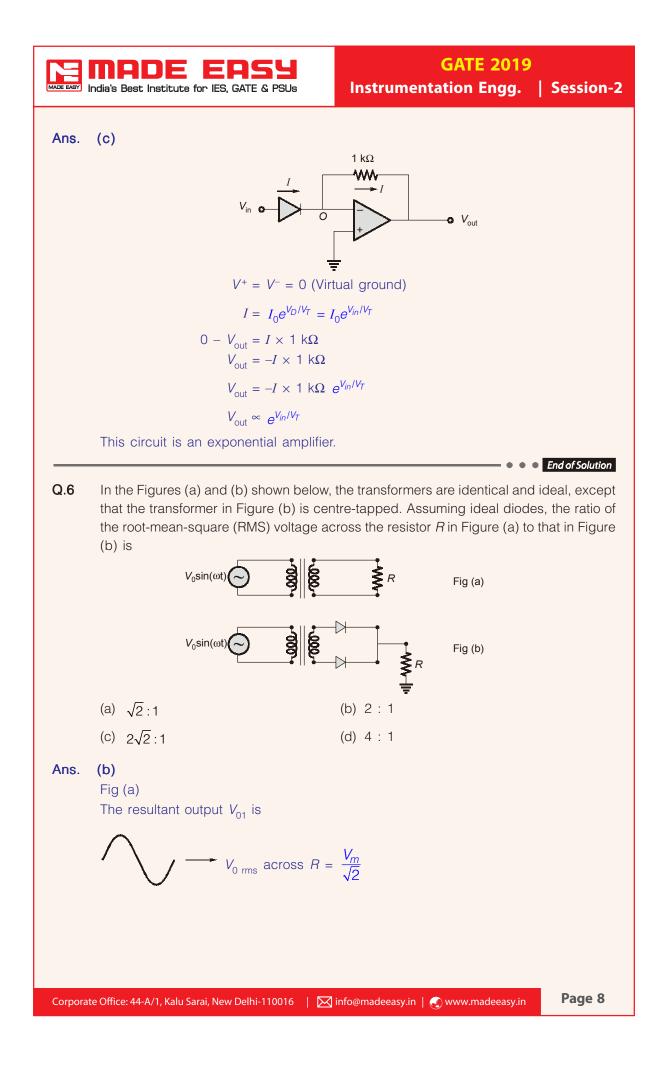
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	ESE 2019 Mains Offline Test Series	Rs. 3,500/- Rs. 2,500/-	Rs. 4,500/- Rs. 3,500/-	
		<b>Rs. 1000/-</b> Discount on test series va	alid till <b>15-02-2019</b>	

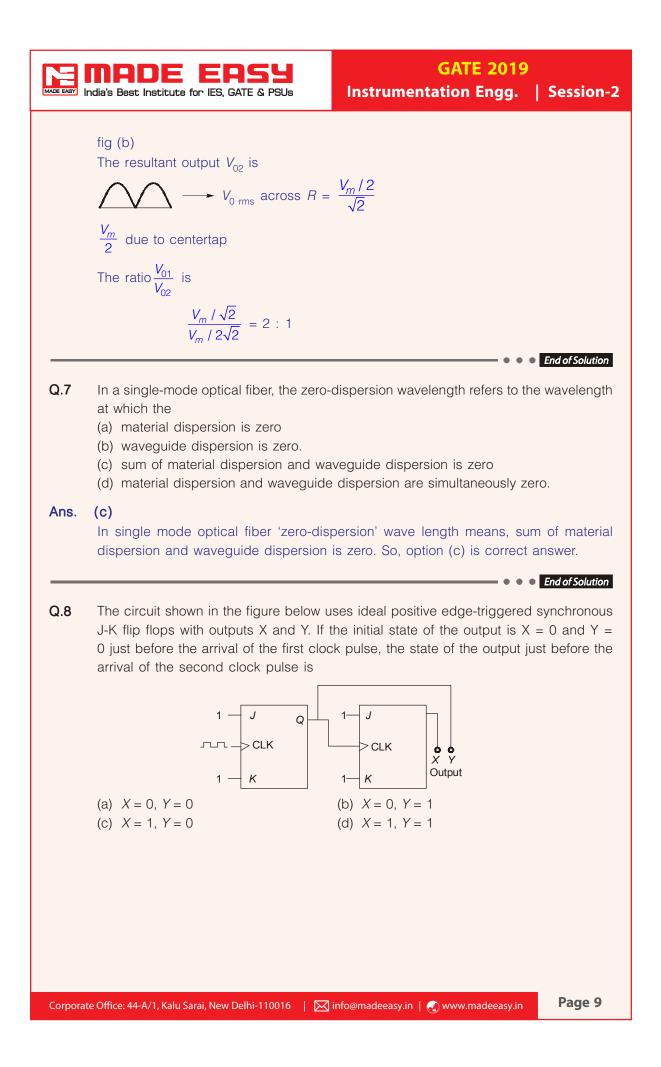
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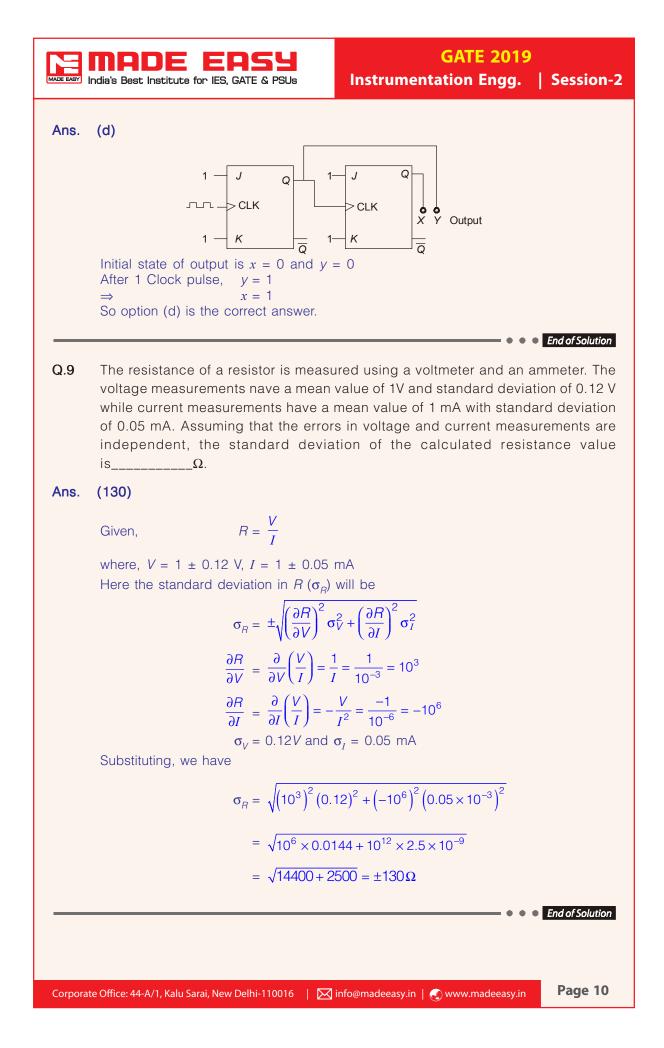
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ME	14-Feb-2019	ME	NA	03-Feb-2019		
EE	18-Feb-2019		23-Feb-2019			
EC	Mid-Feb, 2019		23-Feb-2019	16-Feb-2019		
CS	16-May-2019		17-Feb-2019			

## Rest of India (Regular Batches)

<b>Patna</b> 25-Feb'19	<b>Lucknow</b>	<b>Bhopal</b>	Indore Jaipu		
	20-Feb'19	25-Feb'19	20-Feb'19 17-Feb'		
<b>Pune</b>	Hyderabad	Bhubaneswar	Kolkata		
11-Feb'19	17-Feb'19	25-Feb'19	2-Mar'19		

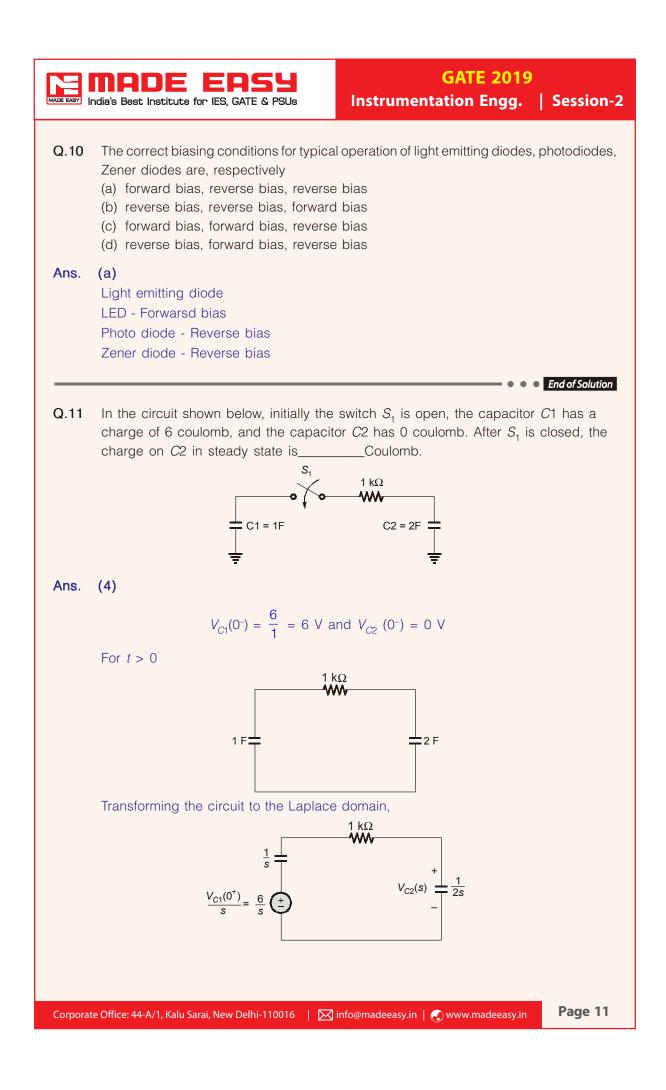
## **Admission open**

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$$V_{C2}(s) = \frac{\frac{6}{s}}{\frac{1}{s} + 1k + \frac{1}{2s}} \times \frac{1}{2s} = \frac{6}{s[2 + 2sk + 1]}$$

Voltage across the capacitor C2 in steady state,

$$V_{C2}(\infty) = \lim_{s \to 0} s V_{C2}(s) = \lim_{s \to 0} \frac{6}{[2 + 2sk + 1]} = \frac{6}{3}$$

$$V_{C2}(\infty) = 2$$

:. The charge on  $C_{2}$  in steady state, Q =  $C_{2}V_{C2}(\infty)$ 

$$Q = (2)(2) = 4C$$

Alternate method :

 $Q_1(0^-) = 6C$  $V_{C_1}(0^-) = \frac{Q_1(0^-)}{C} = \frac{6}{1} = 6V$ 

The initial voltage across the capacitor  $C_1$  is 6V and capacitor  $C_2$  is 0V i.e.  $V_{C_2}(0^-) = 0V$ In steady state the voltage across two capacitors are equal i.e.

$$V_{C_{1}}(\infty) = V_{C_{2}}(\infty) = \frac{V_{C_{1}}(0^{-})C_{1} + V_{C_{2}}(0^{-})C_{2}}{C_{1} + C_{2}}$$
$$V_{C_{1}}(\infty) = V_{C_{2}}(\infty)$$
$$\frac{(6 \times 1) + 0}{1 + 2} = 2V$$

 $\Rightarrow$ 

The steady state voltage across capacitor  $C_2$  is 2V and change  $Q_2 = C_2V_2 = 2 \times 2 = 4C$ 

End of Solution

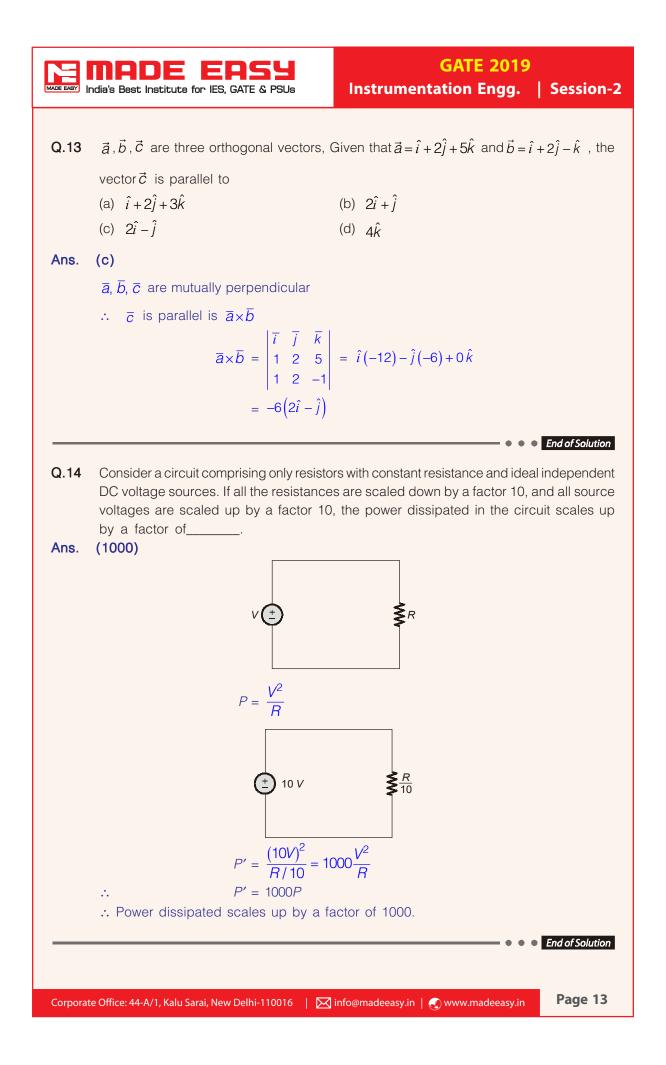
Q.12 The total number of Boolean functions with distinct truth tables that can be defined over 3 Boolean variables is\_\_\_\_\_.

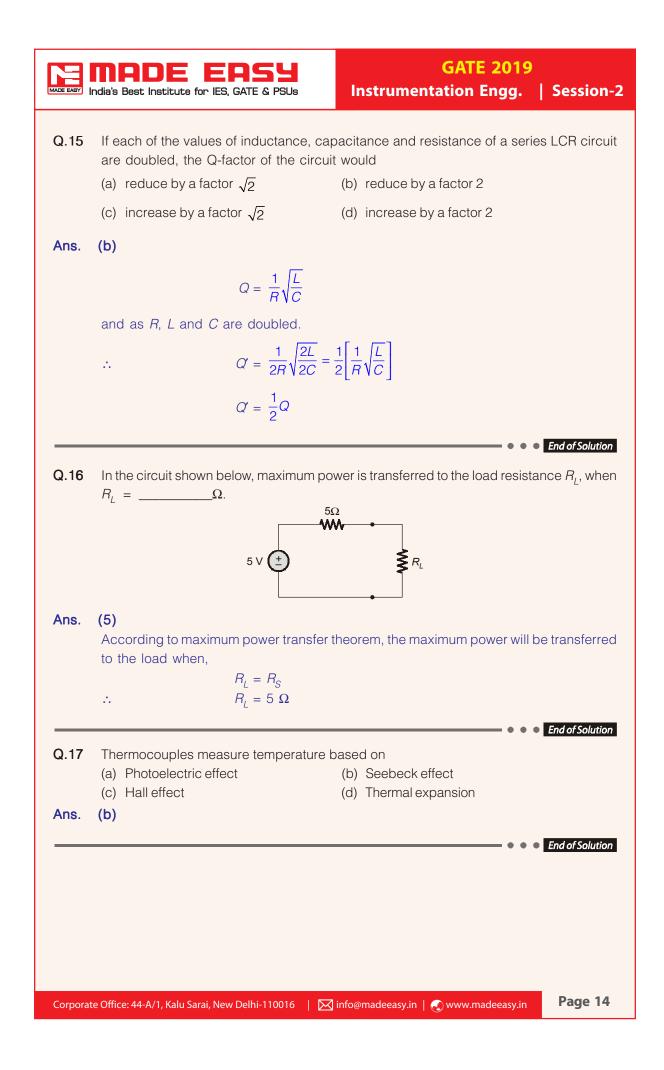
#### Ans. (256)

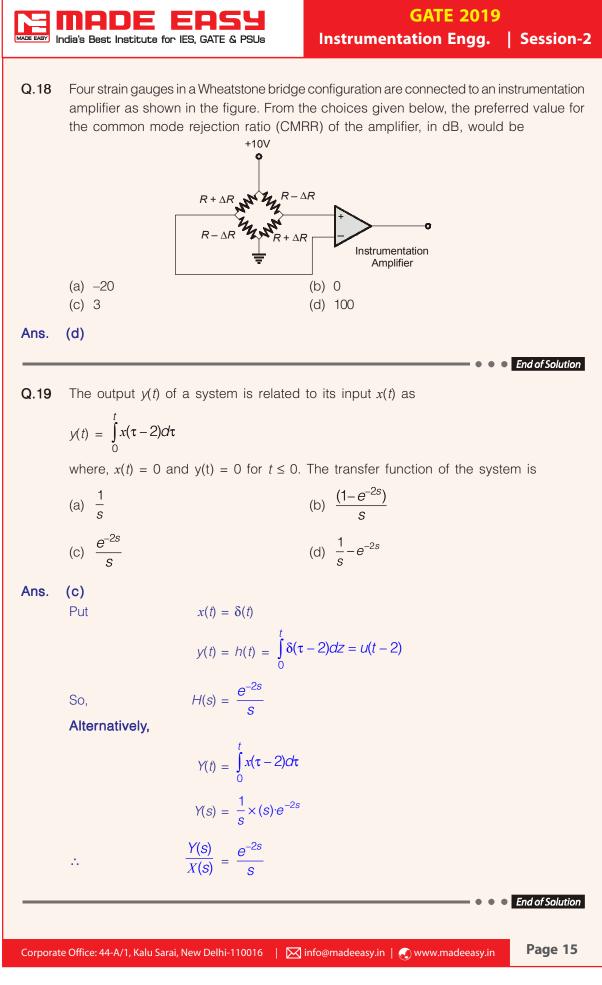
The total number of Boolen function with distinct truth table will be for n Boolen variables

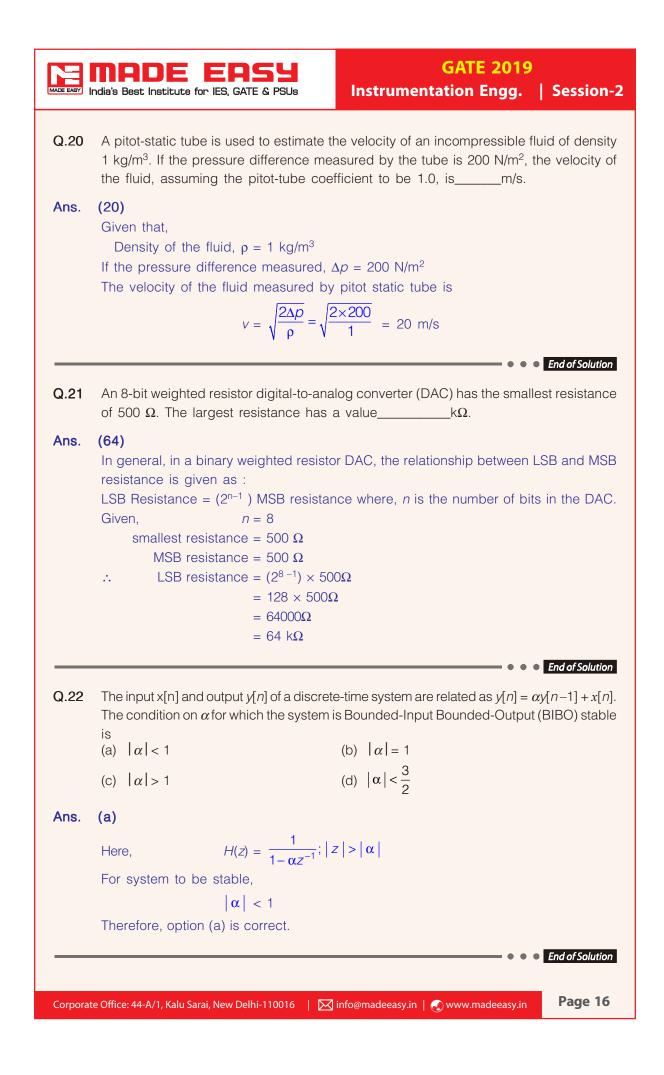
 $(2^{2^n})$  so for 3 Boolen variables =  $(2^{2^3}) = 256$ 

End of Solution







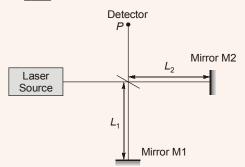


Q.23	A signal $\cos(2\pi f_m t)$ modulates a carrier $\cos(2\pi f_c t)$ using the double-sideband-with carrie (DSBWC) scheme to yield a modulated signal $\cos(2\pi f_c t) + 0.3\cos(2\pi f_m t)\cos(2\pi f_c t)$ . The modulation index is(Answer should be rounded off to one decimal place
Ans.	(0.3) Double sideband with carrier signal is given by
	$s(t) = \cos(2\pi f_c t) + 0.3\cos(2\pi f_m t)\cos(2\pi f_c t)$
	$= \left[1 + 0.3\cos(2\pi f_m t)\right]\cos 2\pi f_c t$
	Comparing with standard amplitude modulated signal
	$s(t) = A_c \left[ 1 + \mu \cos 2\pi f_m t \right] \cos 2\pi f_c t$
	$\mu = 0.3$
	• • End of Solutio
Q.24	In a cascade control system, the closed loop transfer function of the inner loop may be assumed to have a single time-constant $\tau_1$ . Similarly, the closed loop transfer function of the outer loop may be assumed to have a single time-constant $\tau_2$ . The desired relationship between $\tau_1$ and $\tau_2$ in a well-designed control system is (a) $\tau_1$ is much less than $\tau_2$ (b) $\tau_1$ is equal to $\tau_2$ (c) $\tau_1$ is much greater than $\tau_2$ (d) $\tau_1$ is independent of $\tau_2$
Ans.	(a) In a Cascade control system, inner loop should function fast compared to the outerloop Infact it is the basic characteristic of cascade control startergy. Generally speed of response of loop is inversely propertional to time constant of the transfer function. So, time constant of inner loop $\tau_1$ should be less compared to the time constant of outer loop $\tau_2$ . Option (a) is correct answer.
Q.25	• • • End of Solutio
Ans.	(10)
	Product of eigen values = $ A $
	= (1) (2) (5) = 10
	• • • End of Solutio



#### Q.26 - Q.55 Carry Two Mark each.

Q.26 Consider a Michelson interferometer as shown in the figure below. When the wavelength of the laser light source is switched from 400 nanometer to 500 nanometer, it is observed that the intensity measured at the output port P goes from a minimum to a maximum. This observation is possible when the smallest path difference between the two arms of the interferometer is\_\_\_\_nanometer.



#### Ans. (1000)

As per the question the optical path difference in both the cases (400 nm or 500 nm) should be same but for 400 nm wavelength we should get distructive interference whereas for 500 nm wavelength we should get constructive interference.

:. For constructive intereference optical path difference  $(2x) = n\lambda_c$ 

For distructive interference optical path difference  $(2x) = \frac{(2m+1)\lambda_D}{2}$ 

As per question,

$$h\lambda_{\rm c} = \frac{(2m+1)\lambda_D}{2}$$
  
(500) = 
$$\frac{(2m+1)400}{2}$$

 $\therefore$  For n = 2 or m = 2 condition satisfied

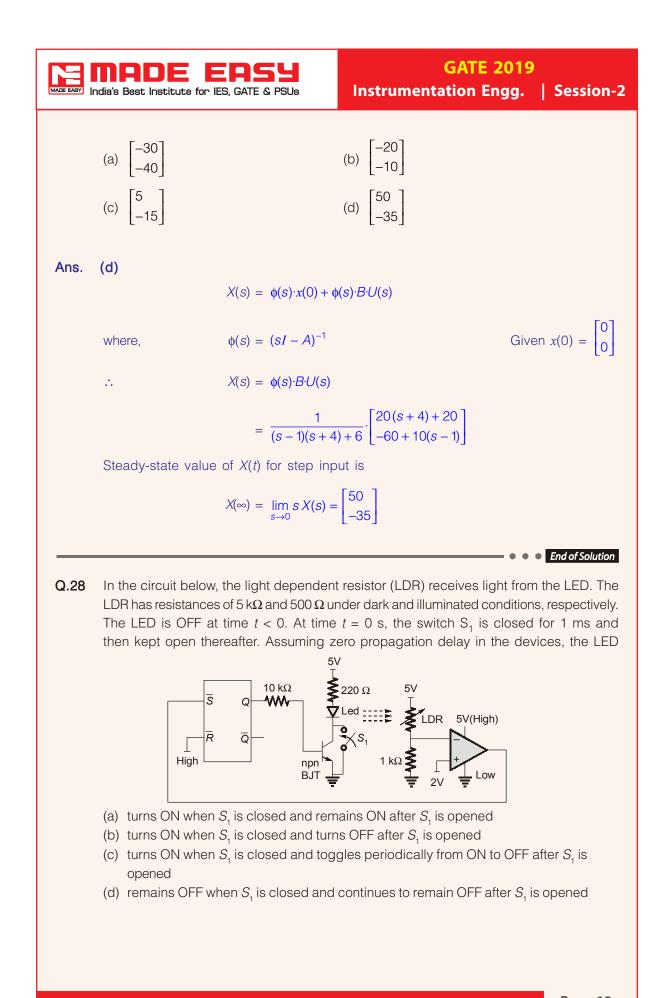
n

: Optical path difference

$$2x = n\lambda$$
  
= 2(500 nm)  
= 1000 nm

**Q.27** The dynamics of the state 
$$\begin{bmatrix} x_1 \\ x_2 \end{bmatrix}$$
 of a system is governed by the differential equation  
 $\begin{bmatrix} \dot{x}_1 \\ \dot{x}_2 \end{bmatrix} = \begin{bmatrix} 1 & 2 \\ -3 & -4 \end{bmatrix} \begin{bmatrix} x_1 \\ x_2 \end{bmatrix} + \begin{bmatrix} 20 \\ 10 \end{bmatrix}$   
Given that the initial state is  $\begin{bmatrix} 0 \\ 0 \end{bmatrix}$ , the steady state value of  $\begin{bmatrix} x_1 \\ x_2 \end{bmatrix}$  is  
**Page 18**

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#### Ans. (a)

When switch  $S_1$  is closed, a conducting path will be formed from  $V_{cc}$  to ground irrespective of the operating condition of the BJT. So, LED turns ON.

In this situation, LDR will have a resistance of 500  $\Omega$ . Voltage at the inverting terminal of the op-amp is,

$$V^{-} = \frac{1000}{1000 + 500} \times 5V = 3.33V$$
  

$$V^{+} = 2V$$
  

$$V^{-} > V^{+}$$
  

$$V_{\text{out}} = 0 \text{ V (logic - LOW)}$$

 $\Rightarrow$ 

So,  $\overline{S}$  will be at logic - LOW at  $\overline{R}$  will be at logic -HIGH. It pulses Q to logic-HIGH, which causs to flow some current into the base terminal of the BJT.

#### When swith $S_1$ is opened after 1 ms:

Now, let us assume that LED is in OFF state. To check the validity of this assumption, we have to check whether current is flowing into the base terminal of the BJT. When LED is in OFF state, LDR will have a resistance of  $5 k \Omega$ .

$$V^{-} = \frac{1}{1+5} \times 5V = 0.83V$$
$$V^{+} = 2V$$
$$V^{-} < V^{+}$$
$$V_{out} = 5 V (logic - HIGH)$$

 $\Rightarrow$ 

So,  $\overline{S}$  will be at logic - HIGH at  $\overline{R}$  will be at logic -HIGH. It pulses Q to be in previous state (i.e., logic -HIGH). This makes the transistor to be in ON state and in turn LED will be in ON state.

So, our assumption is wrong, i.e., the LED will not be in OFF state after  $S_1$  is opened. Hence, LED will be in ON state both during the switch  $S_1$  is closed and after it is opened.

End of Solution

Q.29 In a control system with unity gain feedback, the transfer function of the loop-gain function

is  $L(s) = \frac{9e^{-0.1s}}{s}$ . The phase margin of the loop-gain function L(s) is\_\_\_\_\_\_degrees.

Ans. (38.43)

$$G(s) = \frac{9e^{-0.1s}}{s}$$
$$PM = 180^{\circ} + \left[-90^{\circ} - 0.1\omega \times \frac{180^{\circ}}{\pi}\right]_{\omega = \omega_{g}}$$
$$\omega_{\alpha c} = 9 \text{ r/s}$$

$$\therefore$$
 Phase margin = 38.43°

End of Solution





# Admission Open in Classroom Course for RRB-JE (CBT-1)

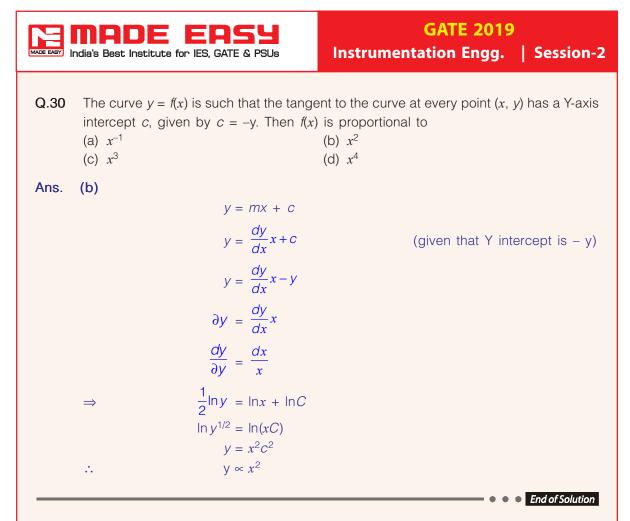
Classroom Centres : Delhi Lucknow Patna

## Batches commencing from 15<sup>th</sup> Feb, 2019 All streams are eligible

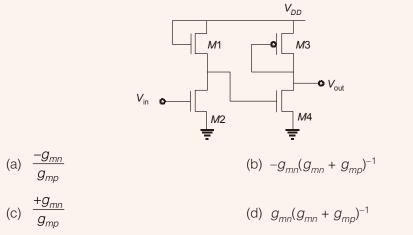
Fee Structure : Classroom Course (RRB-JE)								
Exam	Course Duration	Timing	Freshers	<b>Ex. MADE EASY Students</b> Enrolled in any classroom/postal courses				
CBT 1 (only)	50 Days (180-200 hours)	7 days a week 4 hours per day	Rs. 10,170 + GST = Rs. 12,000/-	Rs. 7,628 + GST = Rs. 9,000/-				

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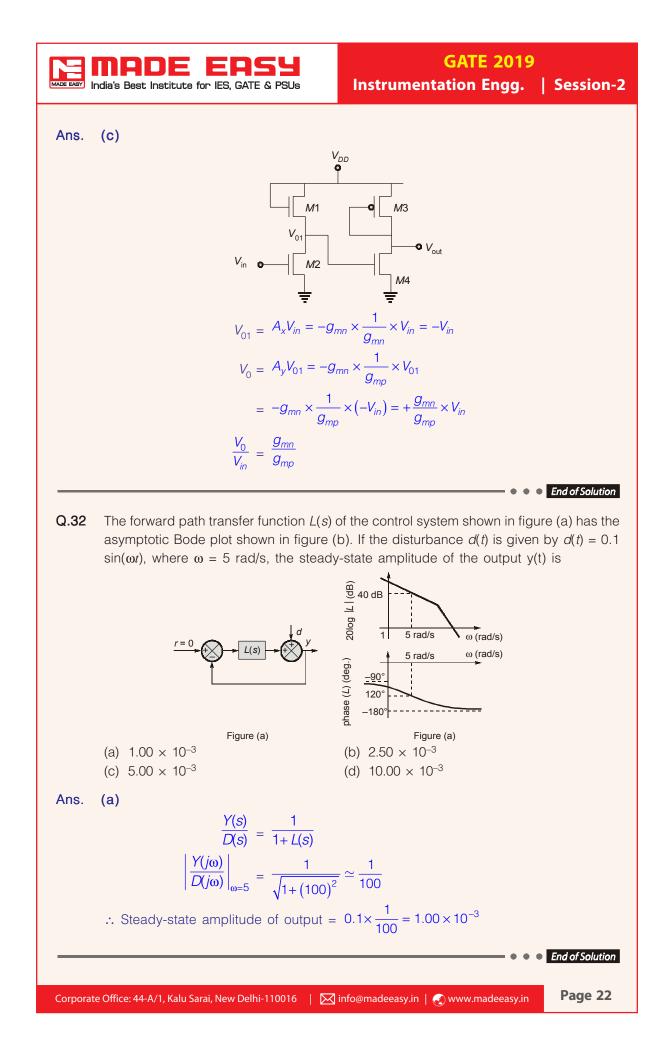
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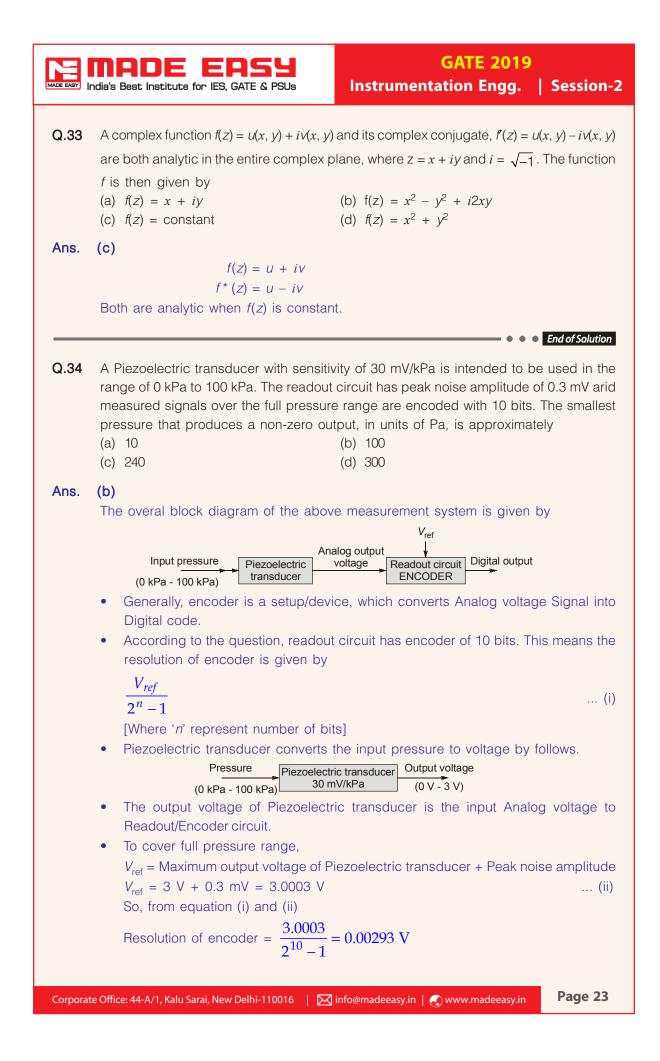


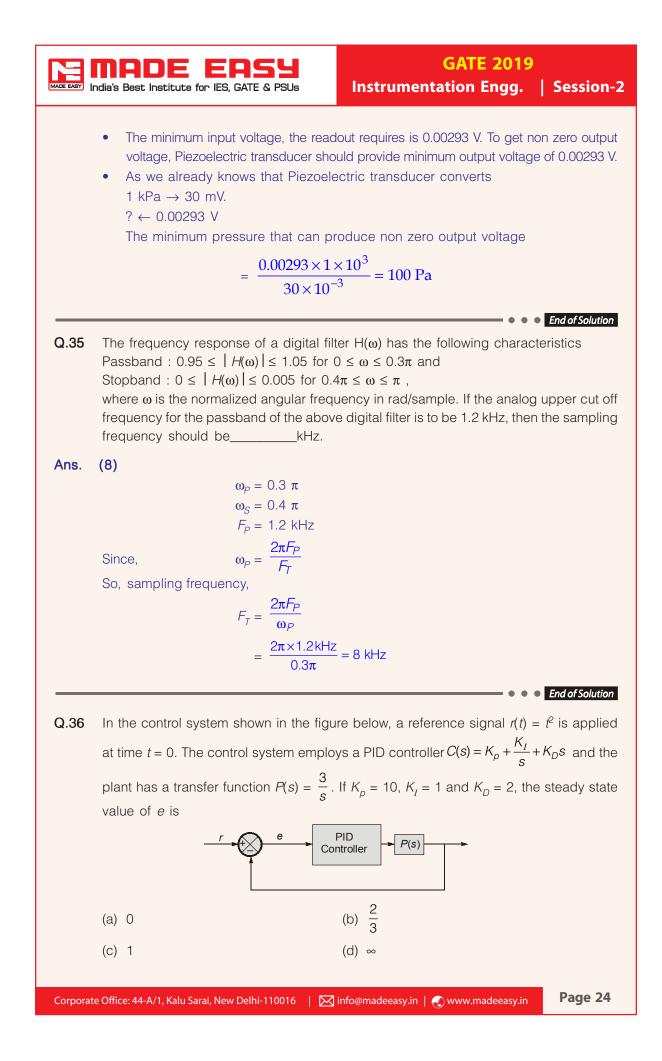
**Q.31** A voltage amplifier is constructed using enhancement mode MOSFETs labeled  $M_1$ ,  $M_2$ ,  $M_3$  and  $M_4$  in the figure below.  $M_1$ ,  $M_2$  and  $M_4$  are *n*-channel MOSFETs and  $M_3$  is a *p*-channel MOSFET. All MOSFETs operate in saturation mode and channel length modulation can be ignored. The low frequency, small signal input and output voltages are  $v_{in}$  and  $v_{out}$  respectively and the dc power supply voltage is  $V_{DD}$ . All n-channel MOSFETs have identical transconductance  $g_{mn}$  while the p-channel MOSFET has transconductance  $g_{mp}$ . The expressions for the low frequency small signal voltage gain  $v_{out}/v_{in}$  is



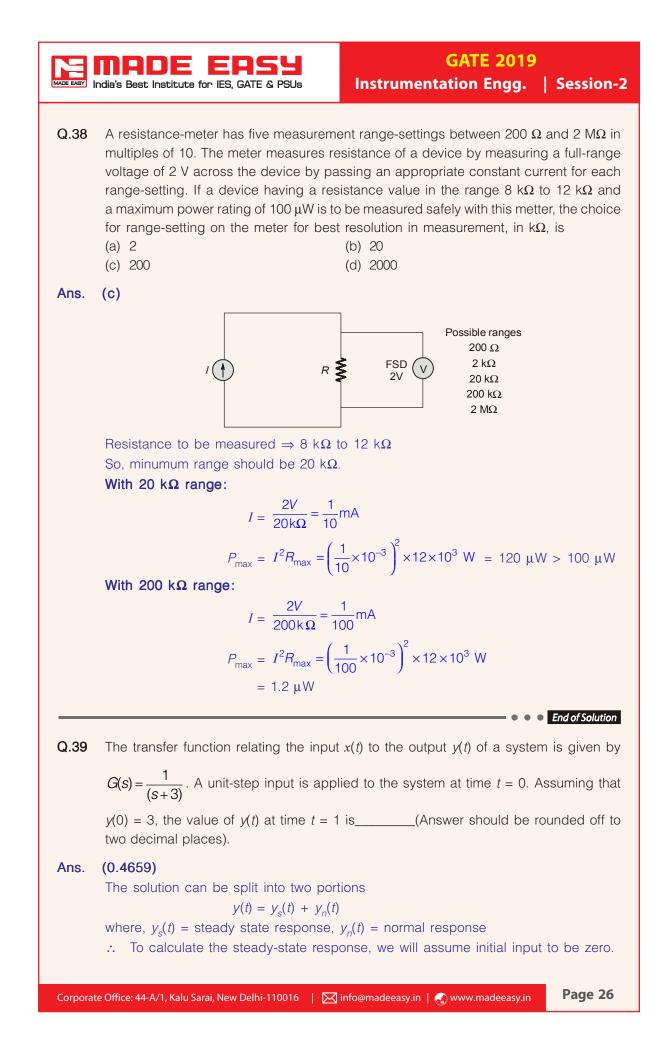
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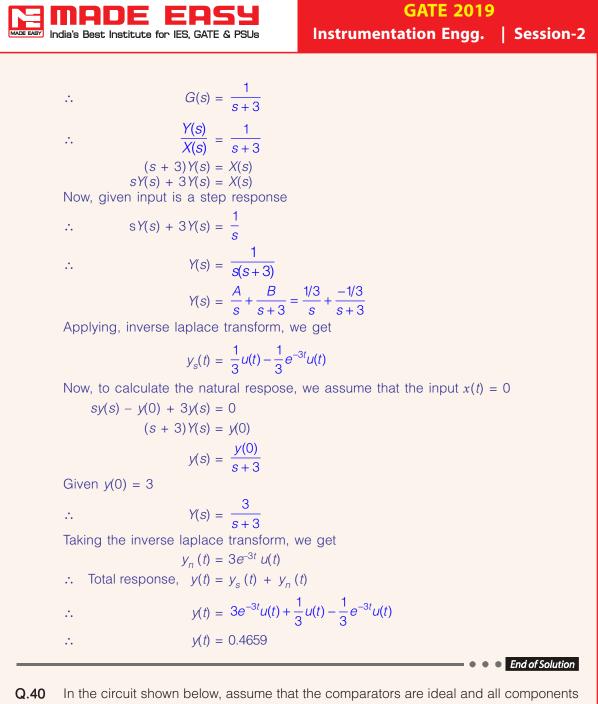




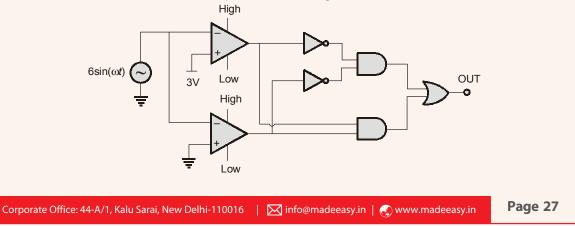


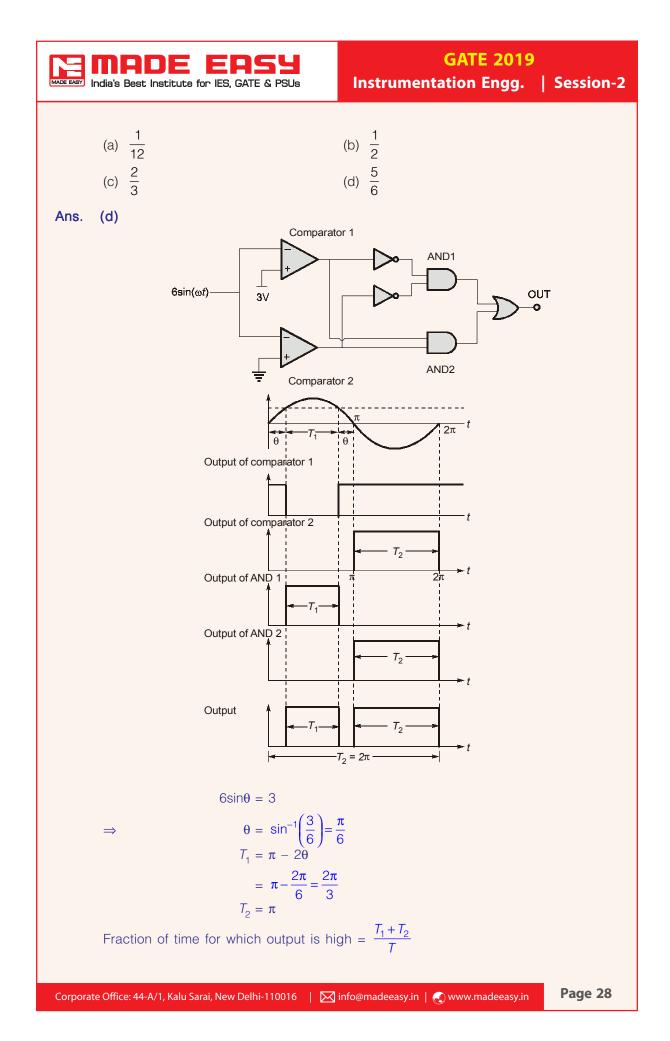
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Ans.	(b) $\frac{E(s)}{R(s)} = \frac{1}{1 + [(PID)(P)]}$ $= \frac{s^2}{3[s^2 + K_P s + K_i + K_D]}$ $\therefore \text{ Steady-state value of } E \text{ is}$ $E(\infty) = \lim_{s \to 0} sE(s)$ $= \lim_{s \to 0} s \cdot \frac{s^2}{3[s^2 + K_P s + K_D]}$ $= \frac{2}{3}$	$\frac{2}{\kappa_i + \kappa_D s^2} \times \frac{2}{s^3}$
Q.37 Ans.	$1 \le x < \infty \text{ and } p(x) = 0 \text{ for } -\infty < x < 1. \text{ For } p(x)$ the value of A should be equal to (a) $\mu - 1$ (b) $\mu + 1$ (c) $\frac{1}{(\mu - 1)}$ (d) $\frac{1}{(\mu + 1)}$	to be a probability density function,
	$\int_{-\infty}^{\infty} f(x) dx = 1$ $\int_{-\infty}^{1} f(x) dx + \int_{1}^{\infty} f(x) dx = 1$ $0 + \int_{1}^{\infty} \frac{A}{x^{\mu}} dx = 1$ $A\left(\frac{x^{-\mu+1}}{-\mu+1}\right)\Big _{1}^{\infty} = 1$ $\frac{A(0-1)}{1-\mu} = 1$ $A = \mu - 1$	
Corpora		••• End of Solution sy.in www.madeeasy.in Page 25



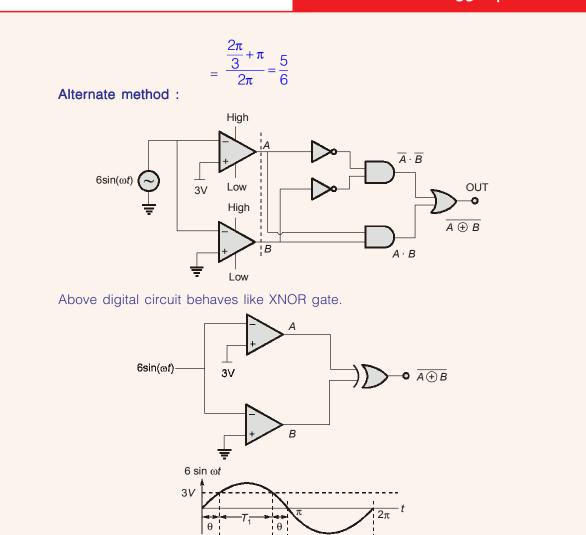


**Q.40** In the circuit shown below, assume that the comparators are ideal and all components have zero propagation delay. In one period of the input signal  $V_{in} = 6 \sin(\omega t)$ , the fraction of the time for which the output OUT is in logic state HIGH is









 $|-T_1 \rightarrow |$ 

 $\theta = \sin^{-1}\left(\frac{3}{6}\right) = \frac{\pi}{6}$ 

 $-T = 2\pi$ 

 $T_1 = \pi - 2\theta = \pi - \frac{2\pi}{6} = \frac{2\pi}{3}$ 

В

Out

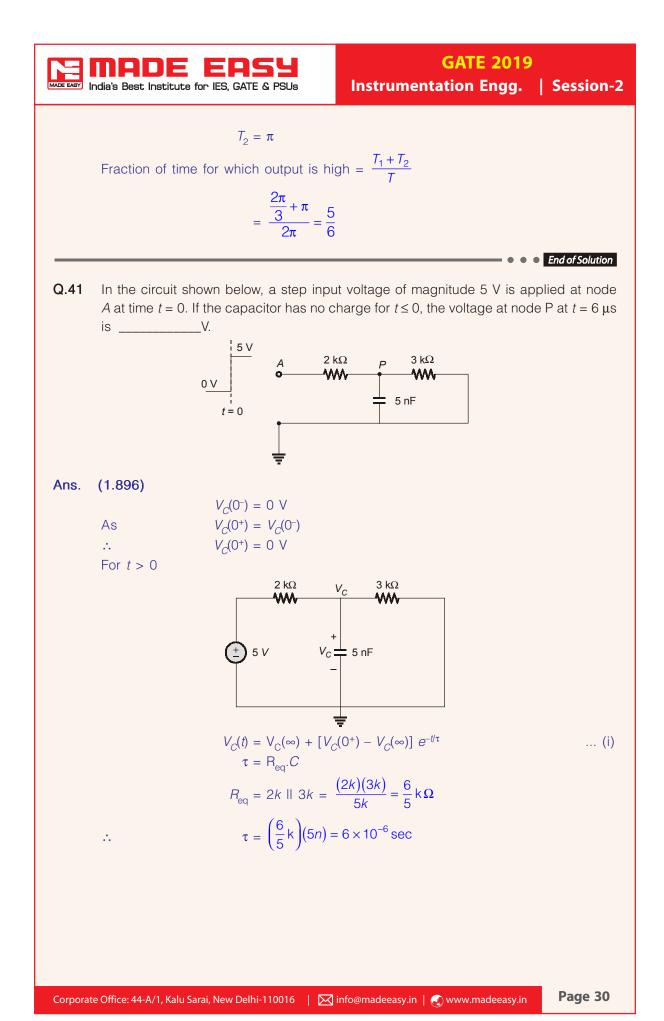
 $6 \sin\theta = 3$ 

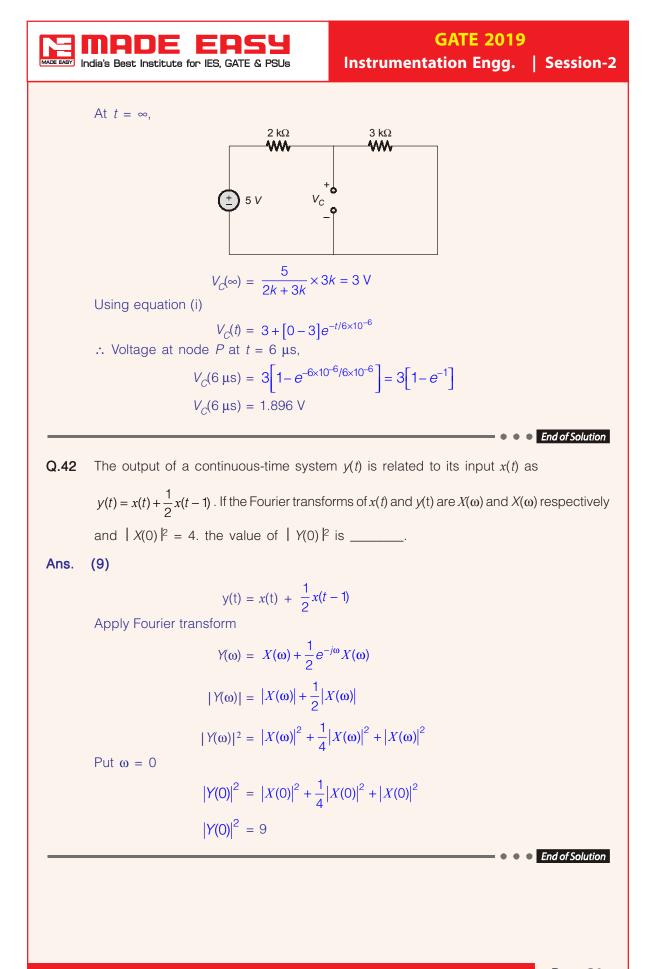
 $\Rightarrow$ 

Page 29

- t

 $-T_2 = \pi -$ 







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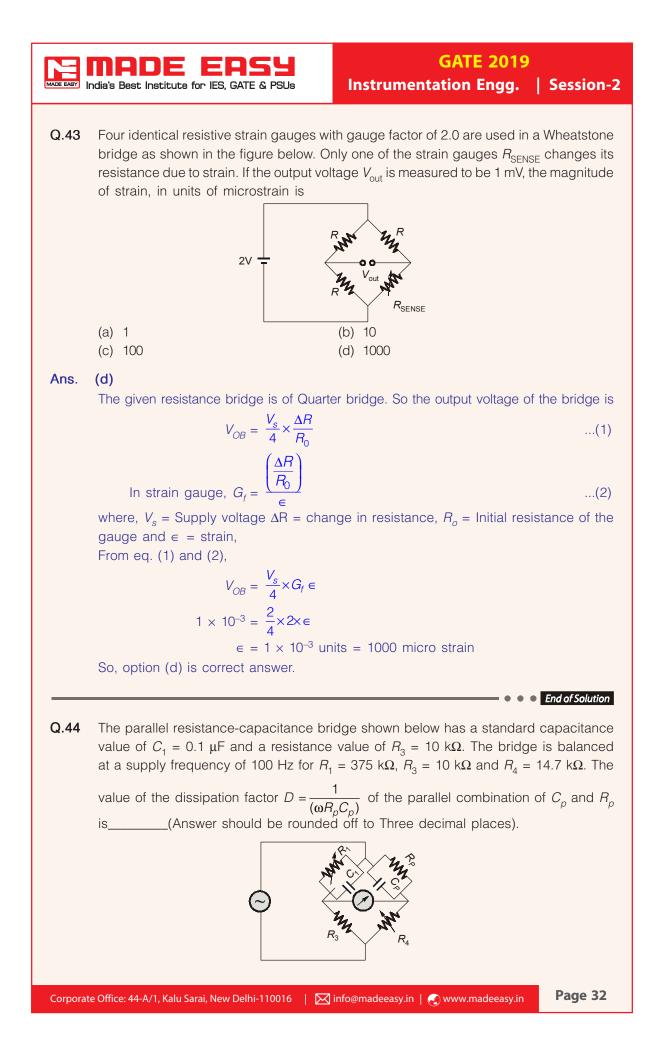
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ns.	(0.0424)			
	• •	bridge circuit,		
		$Z_1 = \frac{R_1}{1+j\omega C_1 R_1}$		
		$Z_2 = \frac{R_P}{1 + i\omega C_P R_P}$	_	
		$Z_3 = R_3$ $Z_4 = R_4$		
	At balance co			
		$Z_1 Z_4 = Z_2 Z_3$		
		$\frac{R_1 R_4}{1 + j \omega C_1 R_1} = \frac{R_P R_3}{1 + j \omega C_P R_P}$		
	1 7 1	$\omega C_P R_P R_1 R_4 = R_P R_3 + j \omega C_P R_2$ ne real and imaging comp	1 7 1 0	
		$R_1 R_4 = R_P R_3$ or $R_P$	$y = \frac{R_1 R_4}{R_3}$	
		$C_P R_4 = C_1 R_3$		
	or	$C_P = \frac{C_1 R_3}{R_4}$		
	Given,	$D = \frac{1}{\omega C_P R_P} = \frac{1}{\omega C_P R_P}$	$\frac{1}{\omega} \times \frac{R_4}{C_1 R_3} \times \frac{R_3}{R_1 R_4} = \frac{1}{\omega C_1 R_1}$	
	Given,	$C_1 = 0.1 \times 10^{-6} \text{F}$ $\omega = 2 \times \pi \times 10$	$F; R_1 = 375 \times 10^3 \Omega$ 0 = 628.318	
		$D = \frac{1}{628.318 \times 10^{-2}}$	$\frac{1}{0.1 \times 10^{-6} \times 375 \times 10^3} = 0.0424$	
.45	A discroto tim	period $r[n] = e^{j\left(\frac{5\pi}{2}\right)n} + e^{j\left(\frac{5\pi}{2}\right)n}$	$\left(\frac{\pi}{4}\right)^n$ is down-sampled to the signal	• End of Solution

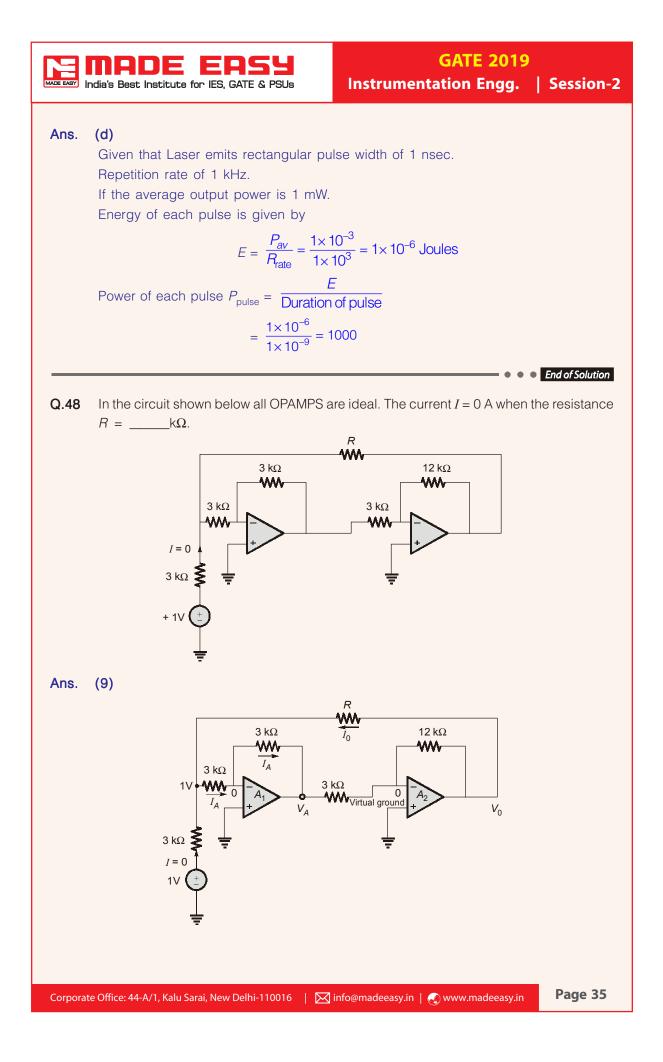
Ans. (6)

GCD ( $\omega_1, \omega_2$ )

$$x(n) = e^{j(5\pi/3)n} + e^{j(\pi/4)n}$$
$$\omega_1 = \frac{5\pi}{3}$$
$$\omega_2 = \frac{\pi}{4}$$
$$\omega_0 = \frac{\pi}{12}$$

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	$x_d(n) = x(4n)$ Apply time scaling so, $\omega_d = 4\omega_0 = \frac{4\pi}{12} =$	$\frac{\pi}{3}$	
	$\Rightarrow \qquad \frac{\omega d}{2\pi} = \frac{m}{N}$ $\Rightarrow \qquad \frac{\pi/3}{2\pi} = \frac{m}{N}$ $N = 6$		
Q.46	A 100 W light source emits uniformly in a active area whose diameter is 2 cm is p incident light. If the responsivity of the generated in the detector, in units of m (a) 1 (c) 100	laced 1 m away from the source, photodetector is 0.4 A/W, the p	normal to the
Ans.	(a)	(Deweer)	
	Intensity of light at photo detector =	$\left(\frac{\text{Power}}{4\pi d^2}\right) W/m^2$	
	where <i>d</i> is distance in meters = $\frac{100}{4\pi(1)^2}$	$\frac{1}{2} = \frac{100}{4\pi} W/m^2$	
	Power received by photodetector = Inte		noto detector
	$= \frac{100}{4\pi} \times \pi \times (0)$	$(0.01)^2 = \frac{1}{400}W$	
	Responsibility = $\frac{\text{Output current}}{\text{Power}}$	ent	
	Output current = Responsivity		
	$=\frac{1}{400} \times 0.4 =$	$\frac{1}{1000}A = 1 \text{ mA}$	
	Hence, answer (a)		
Q.47	A pulsed laser emits rectangular pulses 1 kHz. If the average power output is duration, in Watts, is (a) 1		
	(c) 100	(d) 1000	
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	Opamp A <sub>1</sub> KCLat <i>V</i> -	
	$\frac{1V-0}{3k} = \frac{0-V_A}{3k}$	
	$V_A = -1 V$	
	Opamp $A_2$ KCL at $V^-$	
	$\frac{V_A - 0}{3k} = \frac{0 - V_0}{12k}$	
	$-\frac{1}{3k} = -\frac{V_0}{12k}$	
	$V_0 = 4 V$	
	KCL at 1 V $I_0 + I = I_A$	
	$I_0 = I_A = \frac{1V - 0}{3k}$	$r^{2} = \frac{1}{2} mA$
	OA	0
	$h = \frac{I_0}{I_0} - \frac{I_0}{I_0}$	$\frac{4V - 1V}{\frac{1}{3} \text{ mA}} = \frac{3}{\frac{1}{3} \text{ mA}} = 9 \text{ k}\Omega$
	$R = 9 \ \text{k}\Omega$	
Q.49	to A12 are used to select a 4096 wor to address a particular word in the m	End of Solution ess bus. the most significant address lines A15 d memory unit, while lines A0 to A11 are used emory unit. If the 3 least significant lines of the ed to ground, the addressable number of words
Ans.	(512)	
	Total address line = 16 3 lines grounded	
	4 lines for chip select Remaining lines 9	
	$2^9 = 512$ words.	
Q.50	$X = X_1 X_0$ and $Y = Y_1 Y_0$ are 2-bit binary the condition "If $X > Y$ , then $S = 1$ ",	• • • End of Solution numbers. The Boolean function <i>S</i> that satisfies in its minimized form, is
	(a) $X_1Y_1 + X_0Y_0$	(b) $X_1\overline{Y}_1 + X_0\overline{Y}_0\overline{Y}_1 + X_0\overline{Y}_0X_1$
	(c) $X_1 \overline{Y}_1 X_0 \overline{Y}_0$	(d) $X_1\overline{Y}_1 + X_0\overline{Y}_0Y_1 + X_0\overline{Y}_0\overline{X}_1$

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Ans.	(b)								
	Given	X =	$X_{1}X_{0}$						
	and	Y =	Y <sub>1</sub> Y <sub>0</sub> Y						
	lf								
	Then,	<i>S</i> =							
	The truth table for	r <i>S</i> can I	be dra	awn as	s follov	VS,			
			>		у				
			<i>X</i> <sub>1</sub>	<i>X</i> <sub>0</sub>	<i>y</i> <sub>1</sub>	<i>y</i> <sub>0</sub>	S	-	
		0	0	0	0 0	0 1	0		
		2 3	0	0	1 1	0 1	0		
		4	0	1	0	0	1		
		5 6	0	1	0 1	1 0	0		
		7	0	1	1	1	0		
		8	1	0	0 0	0 1	1		
		10	1	0	1	0	0		
		11 12	1	0	1 0	1 0	0		
		13	1	1	0	1	1		
		14 15	1	1	1 1	0 1	1		
	$S(X_1, X_0,$ The above function		e sim	plified	usking	g k-M		s follows :	
			$\overline{y_1} \overline{y_0}$	ر <u>7</u> 7 بر 1	0 y <sub>1</sub>	2	<i>y</i> <sub>1</sub> <i>y</i> <sub>0</sub>	]	
		$\overline{X}_1 \overline{X}_0$	• 						
		$\overline{X}_1 X_0$	4	5	7	6			
		$X_{1} X_{0}$		13	15		4	+  1	
		$X_1 \overline{X}_0$	8 ¦ <u>! 1</u>	9	11	1	0		
		<i>S</i> =	$X_1\overline{Y}_1$ -	$+ X_0 \overline{Y}_1 \overline{Y}_1$	$\bar{y}_0 + X_1 y$	$X_0 \overline{Y}_0$			
								••	End of Solution

## **General Studies & Engineering Aptitude Batches for ESE 2020** (Preliminary Examination)



ADMISSION OPEN

## **Syllabus Covered**

- 1. Current issues of national and international importance relating to social economic and industrial development.
- 2. Engineering Aptitude covering Logical reasoning and Analytical ability.
- 3. Engineering Mathematics and Numerical Analysis.
- 4. General Principles of Design, Drawing, Importance of Safety.
- 5. Standards and Quality practices in production, construction, maintenance and services.
- 6. Basic of Energy and Environment : Conservation, Environmental pollution and degradation, Climate Change, Environmental impact assessment.
- 7. Basic of Project Management.
- 8. Basics of Material Science and Engineering.
- 9. Information and Communication Technologies (ICT) based tools and their applications in Engineering such as networking, e-governance and technology based education.
- 10. Ethics and values in engineering profession.

<b>Course Duration</b>	Ì	Timings	i	<b>Teaching Hours</b>
Regular Batches : 2.5 months Weekend Batches : 4 months		Regular : 6 to 7 days a week and 4-6 hours a day Weekend : Sat, Sun & public holiday, 8 hours each day		250-300 hours

Batch Type	Commencing Dates	Venue	Timing
Regular Batch	20 <sup>th</sup> Feb, 2019	Ghitorni (Delhi)	8:00 AM to 12:00 PM
Weekend Batch	24 <sup>th</sup> Feb, 2019	Ghitorni (Delhi)	8:00 AM to 5:00 PM
Weekend Batch	24 <sup>th</sup> Feb, 2019	Noida Centre	8:00 AM to 5:00 PM

Fee Structure				
Non-MADE EASY Students	<b>Ex. MADE EASY Students</b> Enrolled in Postal, Rank Improvement, Mains, GS, GATE, GATE + ESE Batches			
₹ 25,000 • GS & Engg Aptitude Books will be issued.	<ul> <li>• GS &amp; Engg Aptitude Books will NOT be issued.</li> <li>• Interested students can avail books by paying the fee of Rs. 2,000/-</li> </ul>			

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